

High precision resistivity mapping

Automated SiC Process Control

Deviations in resistivity within SiC crystals are of significant interest for material processing and quality control. The eddy-current based RESmap device offers high sensitivity and repeatability through integrated temperature compensation and self-calibration routines.

RESmap



Learn more

**Si, SiC,
GaN,
GaAs,
InP and
more**

Materials

Automated X-Y mapping stage

Single and multi-point measurement,
resolution: 1 ± 0.1 mm

Resistivity range

**1–100
mOhm cm**

>20

Wafers/hour
throughput



Freiberg
Instruments



RESmap

w x h x d
465 X 550 X 600 mm

**Wafers,
boules +
ingots
slabs**

Processing geometries

Sigma

<0.15%

Exceptional
repeatability

Compliant with

**SEMI
MF 673**

3

Models: Handheld,
automation ready and
fully automatic with
robotic arms

**Integrated
distance and
temp sensors**

± 5 % accuracy

**Effortless
calibration**

Reducing setup time
and ensuring
long-term reliability